CMOS Digital Integrated Circuits Silicon Monolithic

74VHC125FT,74VHC126FT

1. Functional Description

· Quad Bus Buffer, Non-Inverted 3-State Outputs

74VHC125FT: Quad Bus Buffer 74VHC126FT: Quad Bus Buffer

2. General

The 74VHC125FT/126FT are high speed CMOS QUAD BUS BUFFERs fabricated with silicon gate C2MOS technology.

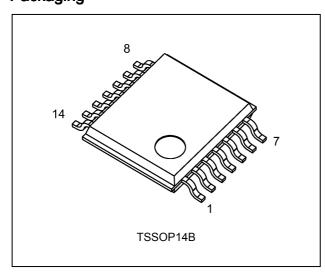
They achieve the high speed operation similar to equivalent Bipolar Shottky TTL while maintaining the CMOS low power dissipation.

The 74VHC125FT requires the 3-state control input \overline{G} to be set high to place the output into the high impedance state, whereas the 74VHC126FT requires the control input G to be set low to place the output into high impedance. An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

3. Features

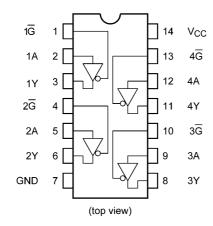
- (1) High speed: Propagation delay time = 3.8 ns (typ.) at $V_{CC} = 5 \text{ V}$
- (2) Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (3) High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- (4) Power down protection is provided on all inputs.
- (5) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (6) Wide operating voltage range: $V_{CC(opr)} = 2 \text{ V to } 5.5 \text{ V}$
- (7) Low noise: $V_{OLP} = 0.8 \text{ V (max)}$
- (8) Pin and function compatible with 74 series (74AC/HC/AHC/LV etc.) 125 or 126 type.

4. Packaging

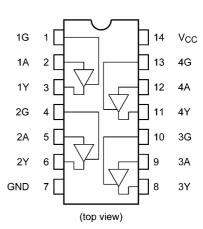


5. Pin Assignment

74VHC125FT

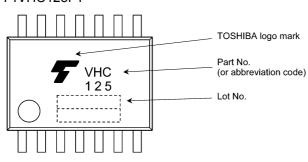


74VHC126FT

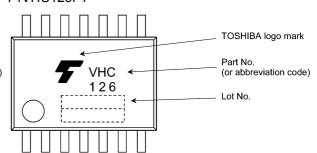


6. Marking



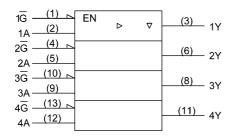


74VHC126FT



7. IEC Logic Symbol

74VHC125FT



74VHC126FT

1G — (1) 1A — (2)	EN	Þ	▽	(3) 1Y
2G (4) 2A (5)				<u>(6)</u> 2Y
3G (10)				(8)3Y
4G (13)				<u>(11)</u> 4Y
4A — (12)	l			



8. Truth Table

Input G (74VHC125)	Input G (74VHC126)	Input A _n	Output Y _n
Н	L	X	Z
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	-0.5 to 7.0	V
Input voltage	V _{IN}	-0.5 to 7.0	
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	
Output current	I _{OUT}	±25	
V _{CC} /ground current	I _{CC}	±50	
Power dissipation	P _D	180	mW
Storage temperature	T _{stg}	-65 to 150	Ç

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}		2.0 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	
Output voltage	V _{OUT}		0 to V _{CC}	
Operating temperature	T _{opr}		-40 to 85	°C
Input rise and fall times	dt/dv	V _{CC} = 3.3 ± 0.3 V	0 to 100	ns/V
		V _{CC} = 5 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND.



11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	_	
Low-level input voltage	V _{IL}	_		2.0	_	_	0.50	V
				3.0 to 5.5	_	_	V _{CC} × 0.3	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I _{OH} = -4 mA	3.0	2.58	_	_	
			I _{OH} = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 4 mA	3.0	_	_	0.36	
			I_{OL} = 8 mA	4.5	_	_	0.36	
3-state output OFF-state leakage current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.25	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	_	±0.1	μΑ
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	μΑ

11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				3.0 to 5.5	V _{CC} × 0.7	_	
Low-level input voltage	V _{IL}	_		2.0	_	0.50	V
				3.0 to 5.5	_	V _{CC} × 0.3	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I _{OH} = -4 mA	3.0	2.48	_	
			I _{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.44	
			I _{OL} = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_	±2.50	μА
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	40.0	μА



11.3. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHC125FT	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	_	5.6	8.0	ns
						50	_	8.1	11.5	
					5.0 ± 0.5	15	_	3.8	5.5	
						50	_	5.3	7.5	
	74VHC126FT	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	_	5.6	8.0	
						50	_	8.1	11.5	
					5.0 ± 0.5	15	_	3.8	5.5	
						50	_	5.3	7.5	
3-state output enable time		t_{PZL}, t_{PZH}		$R_L = 1 k\Omega$	3.3 ± 0.3	15	_	5.4	8.0	ns
						50	_	7.9	11.5	
					5.0 ± 0.5	15	_	3.6	5.1	
						50	_	5.1	7.1	
3-state output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	3.3 ± 0.3	50	_	9.5	13.2	ns
					5.0 ± 0.5	50	_	6.1	8.8	
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	3.3 ± 0.3	50	_	_	1.5	ns
					5.0 ± 0.5	50	_	_	1.0	
Input capacitance		C _{IN}		_			_	4	10	pF
Output capacitance		C _{OUT}		_			_	6	_	pF
Power dissipation	74VHC125FT	C _{PD}	(Note 2)	_			_	14	_	pF
capacitance	74VHC126FT						_	15	_	

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLHm} - t_{PLHn}|, t_{osHL} = |t_{PHLm} - t_{PHLn}|)$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per gate)



11.4. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

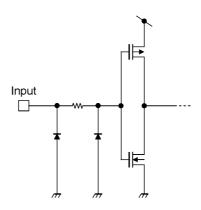
Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHC125FT	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	1.0	9.5	ns
						50	1.0	13.0	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
	74VHC126FT	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	1.0	9.5	
						50	1.0	13.0	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
3-state output enable time		t_{PZL}, t_{PZH}		$R_L = 1 k\Omega$	3.3 ± 0.3	15	1.0	9.5	ns
						50	1.0	13.0	
					5.0 ± 0.5	15	1.0	6.0	
						50	1.0	8.0	
3-state output disable time		t_{PLZ}, t_{PHZ}		$R_L = 1 k\Omega$	3.3 ± 0.3	50	1.0	15.0	ns
					5.0 ± 0.5	50	1.0	10.0	
Output skew		t _{osLH} ,t _{osHL}	(Note 1)	_	3.3 ± 0.3	50		1.5	ns
					5.0 ± 0.5	50		1.0	
Input capacitance		C _{IN}		_			_	10	pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{PLHm} - t_{PLHn}|, t_{osHL} = |t_{PHLm} - t_{PHLn}|)$

11.5. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.3	-0.8	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	
Maximum low-level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0		1.5	

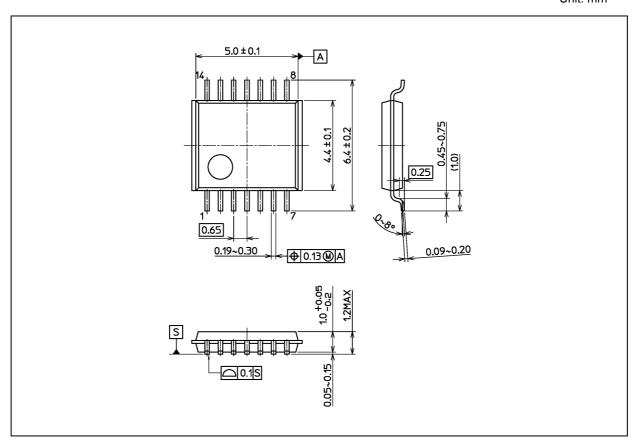
11.6. Internal Equivalent Circuit





Package Dimensions

Unit: mm



Weight: 0.054 g (typ.)

	Package Name(s)
Nickname: TSSOP14B	



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2013-03-28 Rev.1.0